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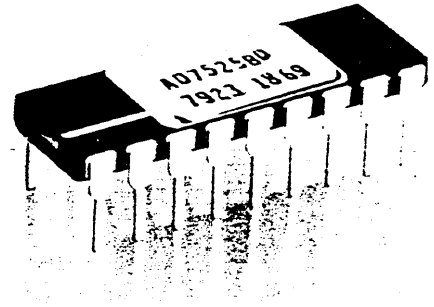
3 1/2 Digit BCD Monolithic CMOS Digitally Controlled Potentiometer

FEATURES

- Resolution: 3 1/2 Digit BCD (1999 Counts)
- Nonlinearity: $\pm 1/2$ LSB T_{min} to T_{max}
- Gain Error: $\pm 0.05\%$ FS
- Excellent Repeatability Accuracy
- Low Power Dissipation

APPLICATIONS

- Thumbwheel Switch Voltage Dividers
- Digitally Controlled Gain Circuits
- Digitally Controlled Attenuators
- BCD Multiplying DACs
- Low Power Converters



GENERAL DESCRIPTION

The AD7525 is a monolithic CMOS 3 1/2 digit BCD digitally controlled potentiometer designed for precision incremental voltage-divider applications.

With the addition of an external op amp, the output can be digitally controlled from 0 to $1.999V_{IN}$ with resolution of $0.001V_{IN}$.

AC or DC voltage up to $\pm 10V$ can be applied to the input providing high application flexibility in fields such as audio gain control, etc.

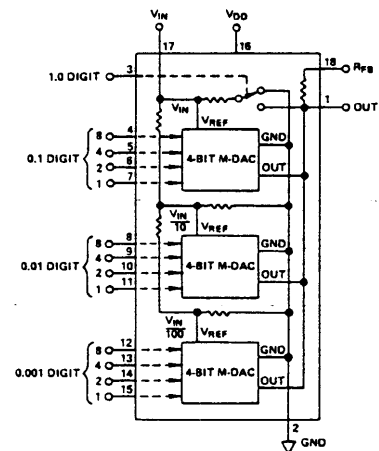
Digital control, excellent repeatability and 0.05% accuracy make the AD7525 an ideal replacement for 10-turn potentiometers or thumbwheel switch voltage dividers using discrete resistor networks.

Packaged in an 18-pin DIP, the AD7525 uses an advanced CMOS fabrication process combined with wafer laser trimming.

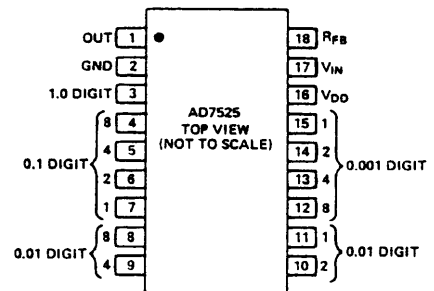
ORDERING INFORMATION

Package and Temperature	Nonlinearity $\pm 1/2$ LSB	Nonlinearity ± 1 LSB
18-Pin Plastic 0 to +70°C	AD7525LN	AD7525KN
18-Pin Ceramic -25°C to +85°C	AD7525CD	AD7525BD
18-Pin Ceramic -55°C to +125°C	AD7525UD	AD7525TD

FUNCTIONAL DIAGRAM



PIN CONFIGURATION



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SPECIFICATIONS

($V_{DD} = +15V$; $V_{PIN1} = 0V$; $V_{IN} = +10V$ unless otherwise stated)

PARAMETER	$T_A = +25^\circ C$	$T_A = \text{Operating Temperature Range}$	CONDITION
ACCURACY			
Resolution ¹	1 part in 2000	1 part in 2000	
Nonlinearity ²			
AD7525KN, BD, TD	±1LSB max	±1LSB max	BCD 0.000 to 1.999
AD7525LN, CD, UD	±1/2LSB max	±1/2LSB max	BCD 0.000 to 1.999
Gain Error ³	±0.05% FS typ	—	BCD = 1.999
Gain TC	±25ppm/ $^\circ C$ max	—	BCD = 1.999
Output Leakage Current (pin 1)	100nA max	400nA max	BCD = 0.0000
DYNAMIC PERFORMANCE			
Switching Time	1 μs max ⁴	1 μs max ⁵	$V_{IN} = +5V$, R_{OUT} (pin 1) = 100 Ω , Digital Inputs = V_{IL} to V_{IH} or V_{IL} , V_{PIN1} measured from 10% to 90%
Feedthrough Error	±0.05% V_{IN} max ⁵	±0.1% V_{IN} ⁵	$V_{IN} = \pm 10V$, 20kHz sinewave
ANALOG INPUT			
Input Resistance (pin 17) ⁶	2k Ω min/10k Ω max	2k Ω min/10k Ω max	
V_{IN} Range (recommended)	±10V max	±10V max	
ANALOG OUTPUT			
Output Capacitance			
C_{OUT} (pin 1)	60pF max ⁵ 200pF max ⁵	60pF max ⁵ 200pF max ⁵	Digital Inputs = BCD 0000 Digital Inputs = BCD 1999
R_{FB} Resistance (pin 18 to pin 1) ⁶	8k Ω min/40k Ω max	8k Ω min/40k Ω max	
DIGITAL INPUTS			
Input HIGH Voltage			
V_{IH}	+14.5V min	+14.5V min	
Input LOW Voltage			
V_{IL}	+0.5V max	+0.5V max	
Input Leakage Current	±1 μA max	±10 μA max	Digital Input = 0V or V_{DD}
Input Capacitance	5pF max ⁵	5pF max ⁵	
Input Coding	3½ Digit BCD (1999 Counts)	3½ Digit BCD (1999 Counts)	
POWER SUPPLY			
V_{DD} Range	+5V to +17V	+5V to +17V	Functional with Degraded Performance
V_{DD}	+15V ±5%	+15V ±5%	Rated Accuracy
I_{DD}	500 μA max	1mA max	Digital Inputs = V_{IL} or V_{IH}

NOTES

¹ Commercial devices are sample tested over temperature.

² Monotonicity is guaranteed on the AD7525LN, CD and UD versions over T_{min} to T_{max} .

³ Gain Error is measured using the AD7525 internal feedback resistor. FS is "Full Scale" (BCD = 1.999).

⁴ AC parameter, sample tested at +25 $^\circ C$ to ensure conformance to specification.

⁵ Guaranteed, not tested.

⁶ Thin-Film resistor temperature coefficient is approximately -300ppm/ $^\circ C$.

Specifications subject to change without notice.

CAUTION

1. ESD (electro-static discharge) sensitive device. The digital control inputs are zener protected; however, permanent damage may occur on unconnected devices subjected to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.
2. Do not apply voltages more negative than GND or more positive than V_{DD} to any pin except V_{IN} (pin 17) and R_{FB} (pin 18).
3. The inputs of some IC amplifiers (especially high speed types) present a low impedance to $V-$ during power sequencing. To prevent the AD7525 OUT terminal (pin 1) from exceeding -300mV (which causes catastrophic substrate current), a Schottky diode, HSCH 1001 or equivalent, is recommended. While not required for most amplifier types, provision for the diode should be made during layout. The diode should be connected between OUT (pin 1) and GND (pin 2) as shown in Figure 4. Protection Schottkys not required when using TRI-FET output amplifiers such as the AD542 or AD544.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

V_{DD} (to GND)	-0.3V, +17V
V_{IN} (to GND)	$\pm 25\text{V}$
R_{FB} (to GND)	$\pm 25\text{V}$
Digital Input Voltage (to GND)	-0.3V to V_{DD}
V_{PIN1} (to GND)	-0.3V to V_{DD}
Power Dissipation (Package)	
Plastic (Suffix N)	
To $+70^\circ\text{C}$	670mW
Derates above $+70^\circ\text{C}$ by	$.8.3\text{mW}/^\circ\text{C}$
Ceramic (Suffix D)	
To $+75^\circ\text{C}$	450mW
Derates above $+75^\circ\text{C}$ by	$.6\text{mW}/^\circ\text{C}$

Operating Temperature

Commercial Plastic (KN, LN Versions)	0 to $+70^\circ\text{C}$
Industrial Ceramic (BD, CD Versions)	-25°C to $+85^\circ\text{C}$
Extended Ceramic (TD, UD Versions)	-55°C to $+125^\circ\text{C}$

TERMINOLOGY

SWITCHING TIME: In a D/A converter, the switching time is the time taken for an analog switch to change to a new state from the previous one. It includes delay time, and rise time from 10% to 90%, but does not include settling time, which is a function of the output amplifier used.

OUTPUT CAPACITANCE: Capacitance from OUT terminal (pin 1) to ground.

FEEDTHROUGH ERROR: Error caused by capacitive coupling from V_{IN} (pin 17) to OUT (pin 1) with all digital inputs LOW.

PRINCIPLES OF OPERATION

CIRCUIT DESCRIPTION

The AD7525, a $3\frac{1}{2}$ digit BCD multiplying DAC, consists of a thin-film R/2R ladder, interquad voltage dividers and 13 N-channel MOS SPDT current steering switches. Most applications require the addition of only an external operational amplifier.

Referring to Figure 1, the "1.0 Digit" is a 1-bit multiplying DAC (composed of SW_1 and R_1) while the 0.1, 0.01, and 0.001 digits are 4-bit multiplying DAC's (DAC1, DAC2, and DAC3) connected by 10:1 dividers (composed of R_{IN2} , R_2 , R_3 and R_{IN3} , R_4 , R_5).

DAC1 is expanded to show the R/2R ladder and switch network. With input voltage V_{IN} , the currents in each shunt arm are (starting at the left) $V_{IN}/2R$, $V_{IN}/4R$, $V_{IN}/8R$ and $V_{IN}/16R$. A logic ONE applied to a digital input steers that shunt arm's current to OUT, while a logic ZERO steers the current to GND.

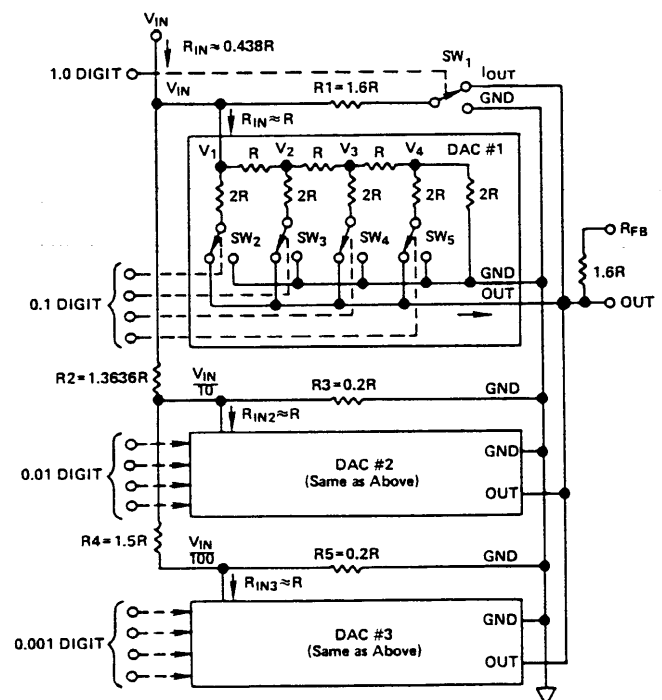


Figure 1. AD7525 Circuit Diagram

EQUIVALENT CIRCUIT

As shown in Figure 2, the AD7525 is a digitally controlled π -network attenuator with signal input "VIN" (pin 17), signal output "OUT" (pin 1), signal common "GND" (pin 2) and digital control "BCD input" (pins 3-15).

With OUT (pin 1) terminated at op amp virtual ground and RFB (pin 18) connected to the op amp output, the nominal transfer equation is:

$$V_{OUT} = -V_{IN} \text{BCD}$$

where $0.000 \leq \text{BCD} \leq 1.999$

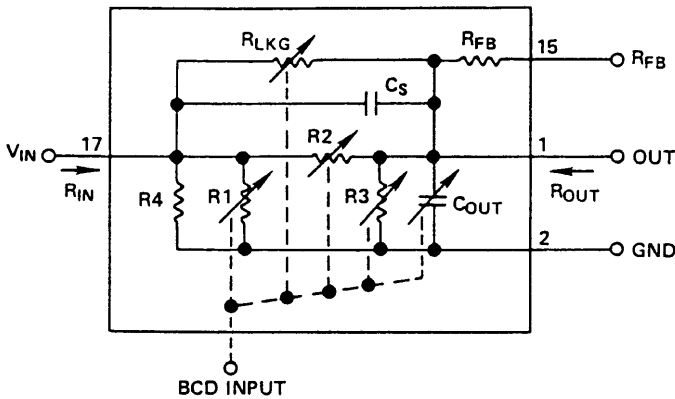


Figure 2. Functional Equivalent Circuit

OUTPUT AMPLIFIER CONSIDERATIONS

Amplifier Offset

The output resistance at OUT (pin 1) is code dependent, varying between ∞ to $0.35 R_{LDR}$. For a fixed feedback resistor of value $1.6 R_{LDR}$ (Figure 3), the output error for a fixed amplifier offset (V_{OS}) is:

$$V_{ERROR} = \left(1 + \frac{R_{FB}}{R_{OUT}}\right) V_{OS}$$

Case 1: ($R_{OUT} = \infty$)

$$V_{ERROR} = \left(1 + \frac{R_{FB}}{\infty}\right) V_{OS}$$

$$V_{ERROR} = V_{OS}$$

Case 2: ($R_{OUT} = 0.35 R_{LDR}$)

$$V_{ERROR} = \left(1 + \frac{1.6 R_{LDR}}{0.35 R_{LDR}}\right) V_{OS}$$

$$V_{ERROR} = (1 + 4.6)V_{OS} = 5.6 V_{OS}$$

Cases 1 and 2 show that amplifier offset in conjunction with a changing output resistance at OUT (pin 1) create nonlinearity error, in addition to a simple offset term.

It is therefore recommended that amplifier initial offset be adjusted to less than $100\mu\text{V}$ (as measured between the amplifier input terminals). The offset voltage over the temperature range of interest should not exceed $250\mu\text{V}$. See application hint #2, below.

Do not include the usual bias current compensation resistor in the amplifier noninverting terminal. Instead, the amplifier should have a bias current which is low over the temperature range of interest. Bias current causes "output offset" of magnitude $(I_B)R_{FB}$.

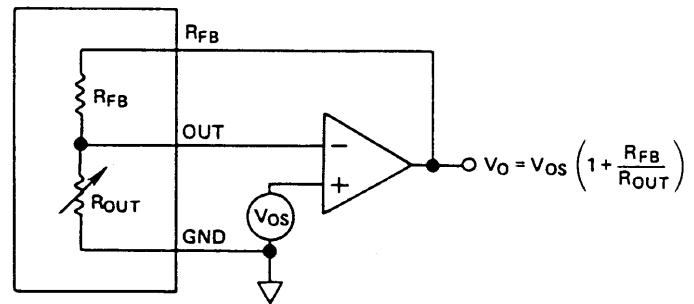


Figure 3. Noise Gain Equivalent Circuit

High Frequency Amplifiers

R_{FB} and C_{OUT} create a phase lag in the output amplifier's feedback circuit. This phase lag, in conjunction with the amplifier's phase lag, may cause ringing or oscillation. When using a high speed amplifier, shunting the amplifier input to output with $5-20\text{pF}$ of feedback capacitance ensures stability.

APPLICATION HINTS

1. If an output voltage range of ± 19.99 volts is required (i.e., AD7525 $V_{IN} = \pm 10\text{V}$, $\text{BCD} = 1.999$), a high voltage output amplifier with appropriate supply voltages must be used.
2. To maintain circuit linearity, the op amp offset voltage should not exceed 2% of the circuit resolution. (Resolution = $V_{IN} \div 1000$)
3. CMOS logic inputs exhibit an input impedance on the order of $100\text{M}\Omega$. Unused CMOS inputs must always be tied to a known logic state. If single-pole single-throw thumbwheel switches are used to drive the digital inputs of the AD7525, external $10\text{k}\Omega$ pull-down (pull-up if switch coding is complementary (BCD) resistors must be used.

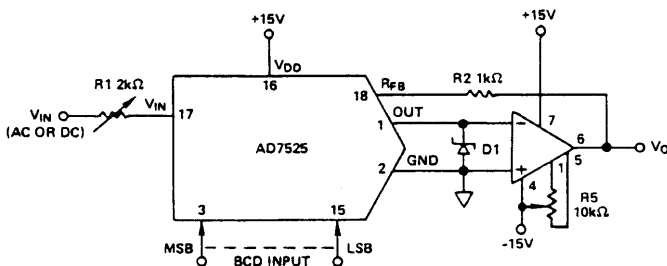


Figure 4. Digitally Controlled Attenuator Circuit

BCD INPUT					ANALOG OUTPUT		
Digital Input					Equivalent	V_O/V_{IN}	V_O
1.0	0.1	0.01	0.001	Decimal Input			
1	1001	1001	1001	1.999	-1.999	$-1.999V_{IN}$	
1	0000	0000	0001	1.001	-1.001	$-1.001V_{IN}$	
1	0000	0000	0000	1.000	-1.000	$-1.000V_{IN}$	
0	1001	1001	1001	0.999	-0.999	$-0.999V_{IN}$	
0	0101	0000	0000	0.500	-0.500	$-0.500V_{IN}$	
0	0000	0000	0000	0.000	0	0	

Note 1:

For proper BCD coding, the 0.1 digit, 0.01 digit or 0.001 digit must not exceed BCD "9" (1001).

Table 1. Analog Input/Output Relationship vs. Digital Input

CALIBRATION PROCEDURE

Offset Adjustment:

1. Apply BCD code 0.000 (0 0000 0000 0000) to the AD7525 digital inputs.
2. Connect a high resolution, high impedance voltmeter between V_O (amplifier output) and pin 2 of the AD7525.
3. Adjust amplifier's trimpot for minimum reading on the voltmeter ($<100\mu V$).

Gain Adjustment:

1. Apply BCD code 1.000 (1 0000 0000 0000) to the AD7525 digital input.
2. Apply +10V to the V_{IN} input of Figure 1.
3. Connect the voltmeter between V_O (amplifier output) and pin 2 of the AD7525.
4. Adjust R_1 until $V_O = -10V$.

APPLICATION - THUMBWHEEL SWITCH ATTENUATOR

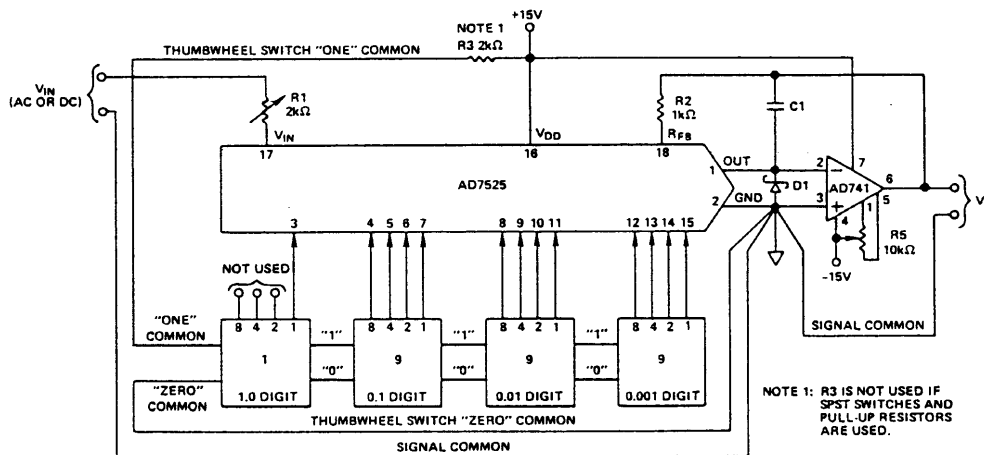


Figure 5. Thumbwheel Switch Attenuator

The circuit shown in Figure 5 is a precision voltage divider similar to 10-turn pots and thumbwheel switch incremental-voltage-divider assemblies. Advantages of the circuit are:

- Economy
- Low Output Impedance
- Resolution 0.1% V_{IN}
- Excellent Repeatability Accuracy
- Overrange Capability

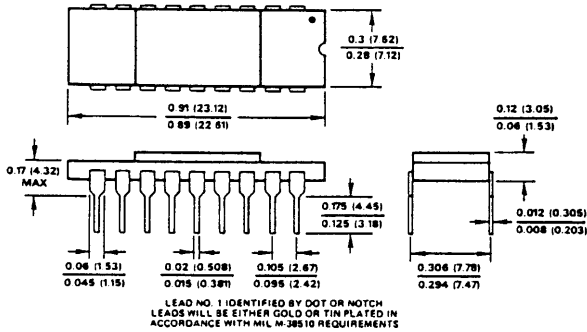
The BCD coded thumbwheel assembly applies BCD data to the AD7525 digital inputs. The switch assembly shown has single-pole-double-throw action, thus the BCD inputs are

pulled either to +15V or GND (available from AMP, Harrisburg, PA; CHERRY, Waukegan, Illinois; or SAE, Santa Clara, California). Resistor R_3 limits current if make-before-break switches are used. SPST switch assemblies can be used; however, appropriate pull-up or pull-down resistors must be used on each digital input, depending upon whether the switch coding is BCD or complementary BCD. This ensures each digital input has appropriate V_{IH} or V_{IL} levels applied.

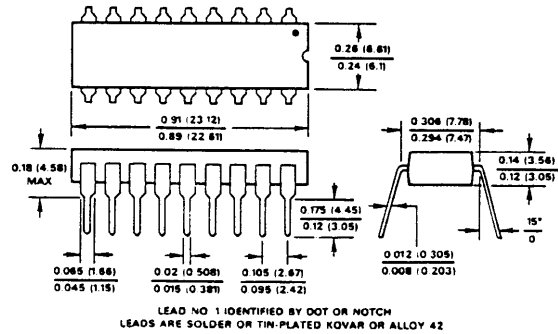
Resistors R_1 and R_2 provide gain adjustment capability. R_5 is used to adjust the amplifier input offset voltage to less than $100\mu V$. Diode D_1 (HSCH 1001) provides AD7525 output protection (see Caution note 3).

MECHANICAL INFORMATION
Dimensions shown in inches and (mm).

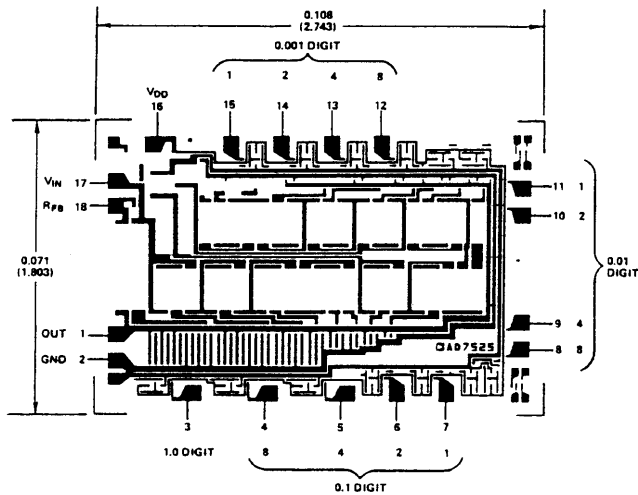
18-PIN CERAMIC DIP



18-PIN PLASTIC DIP



BONDING DIAGRAM



- NOTES:
1. PAD NUMBERS CORRESPOND TO PIN NUMBERS SHOWN IN PIN CONFIGURATION.
2. PAD 2 (GND) SHOULD BE BONDED FIRST TO MINIMIZE ESD HAZARDS.
3. PADS ARE 0.004in x 0.004in (0.102mm x 0.102mm).

SEE ANALOG DEVICES CHIP CATALOG
FOR ADDITIONAL CHIP INFORMATION